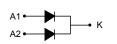
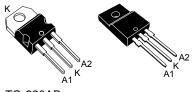


100 V, 20 A power Schottky rectifier

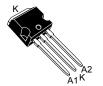




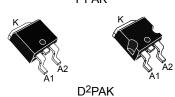
TO-220AB TO-220FPAB

Features

- · Negligible switching losses
- · High junction temperature capability
- · Low leakage current
- Good trade off between leakage current and forward voltage drop
- Avalanche rated
- Insulated package: TO-220FPAB
 - Insulating voltage = 2000 V_{RMS} sine
- ECOPACK[®]2 compliant component for D²PAK on demand



I²PAK



Product status link	
STPS20H100C	

Product summary				
I _{F(AV)}	2 x 10 A			
V _{RRM}	100 V			
T _j (max)	175 °C			
V _F (typ)	0.59 V			

Applications

- · Switching diode
- SMPS
- DC/DC converter
- LED lighting
- Adapter for notebook and game station

Description

Dual center tap Schottky rectifier designed for high frequency miniature switch mode power supplies such as adaptors and on-board DC-DC converters.



1 Characteristics

Table 1. Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified)

Symbol		Parameter				
V _{RRM}	Repetitive peak reverse voltage				100	V
I _{F(RMS)}	Forward rms current				30	Α
		TO 220AB D2DAK 12DAK	To = 160 °C	Per diode	10	
	Average forward current δ = 0.5, square wave	TO-220AB, D ² PAK, I ² PAK	1C = 100 C	Per device	20	
IF(AV)		TO-220FPAB	T _C = 145 °C	Per diode	10	Α
			T _C = 125 °C	Per device	20	
I _{FSM}	Surge non repetitive forward current	tp = 10 ms sinusoidal		,	250	Α
P _{ARM}	Repetitive peak avalanche power tp = 10 μ s, T $_j$ = 125 $^{\circ}$ C				775	W
T _{stg}	Storage temperature range				-65 to + 175	°C
T _j	Maximum operating junction temperature (1)				+ 175	°C

^{1.} $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameter

Symbol		Parameter				
		TO-220AB, D ² PAK, I ² PAK	Per diode	1.6		
D.,	R _{th(j-c)} Junction to case	TO-220FPAB	rei diode	4	°C/W	
r\th(j-c)		TO-220AB, D ² PAK, I ² PAK	Total	0.9		
		TO-220FPAB		3.2		
R., .	R _{th(c)} Coupling	TO-220AB, D ² PAK, I ² PAK		0.15	°C/W	
' `th(c)		TO-220FPAB	_	2.5	C/VV	

When the diodes 1 and 2 are used simultaneously:

 $\Delta Tj(diode 1) = P(diode1) \times R_{th(j-c)}(Per diode) + P(diode 2) \times R_{th(c)}$

For more information, please refer to the following application note:

AN5088: Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit	
I _R ⁽¹⁾	Poverse leakage gurrent	T _j = 25 °C	$V_R = V_{RRM}$	-		4.5	μA	
IR ^(*)	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C $^{\text{VR}}$ $^{\text{VR}}$ $^{\text{VR}}$	VR - VRRM	-	2	6	mA	
	V _F ⁽²⁾ Forward voltage drop	T _i = 25 °C	I _F = 10 A	-		0.77		
V ₋ (2)		Convert veltere dren	1j = 25 C	I _F = 20 A	-		0.88	V
VF ⁽⁻⁾		T _i = 125 °C	I _F = 10 A	-	0.59	0.64	V	
		1 123 0	I _F = 20 A	-	0.67	0.73		

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- 1. Pulse test: t_p = 5 ms, δ < 2%
- 2. Pulse test: t_p = 380 μ s, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 0.55 \times I_{F(AV)} + 0.009 I_{F}^{2}_{(RMS)}$$

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

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1.1 Characteristics (curves)

Figure 2. Average forward current versus ambient temperature (δ = 0.5, per diode) |F(AV)(A)| |F(AV)(A)

Figure 3. Normalized avalanche power derating versus pulse duration (T_j = 125 °C)

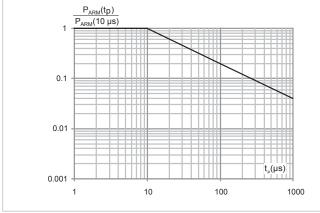


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration

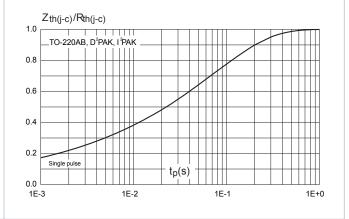


Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

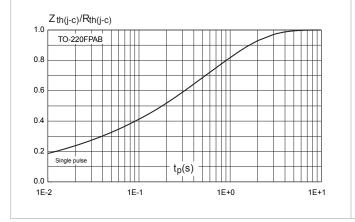
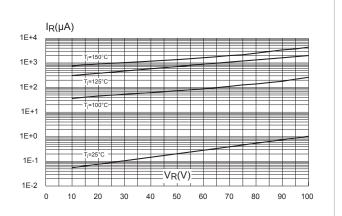


Figure 6. Reverse leakage current versus reverse voltage applied (typical values, per diode)



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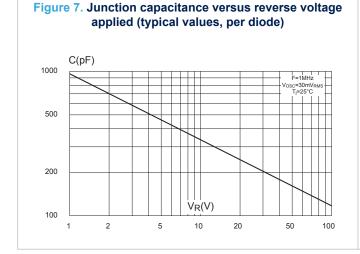


Figure 8. Forward voltage drop versus forward current (maximum values, per diode)

IFM(A)

100.0

IFM(A)

10.0

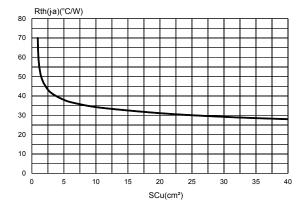
IFM(A)

IFM(B)

IFM(B)

IFM(C)

Figure 9. Thermal resistance junction to ambient versus copper surface under tab (epoxy printed board FR4, e_{Cu} = 35 μ m) (D²PAK)



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2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

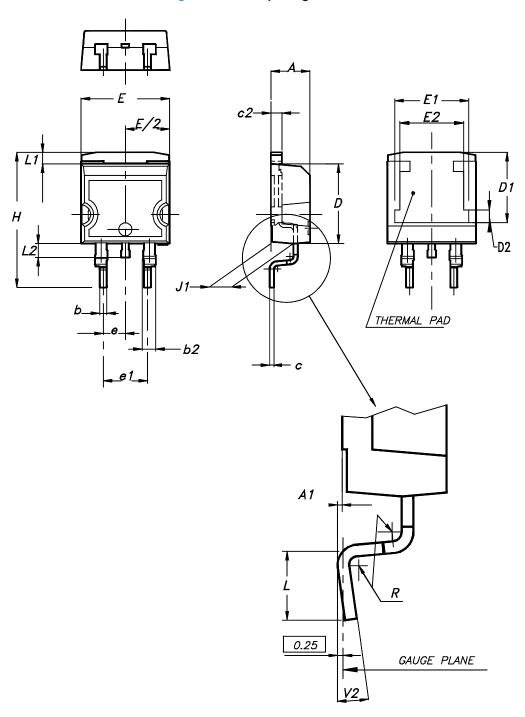
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2.1 D²PAK package information

- Cooling method: by conduction (C)
- Epoxy meets UL 94,V0

Figure 10. D²PAK package outline



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Table 4. D²PAK package mechanical data

	Dimensions			
Ref.	Millim	neters	Inc	hes
	Min.	Max.	Min.	Max.
Α	4.36	4.60	0.172	0.181
A1	0.00	0.25	0.000	0.010
b	0.70	0.93	0.028	0.037
b2	1.14	1.70	0.045	0.067
С	0.38	0.69	0.015	0.027
c2	1.19	1.36	0.047	0.053
D	8.60	9.35	0.339	0.368
D1	6.90	8.00	0.272	0.311
D2	1.10	1.50	0.043	0.060
E	10.00	10.55	0.394	0.415
E1	8.10	8.90	0.319	0.346
E2	6.85	7.25	0.266	0.282
е	2.54	typ.	0.100	
e1	4.88	5.28	0.190	0.205
Н	15.00	15.85	0.591	0.624
J1	2.49	2.90	0.097	0.112
L	1.90	2.79	0.075	0.110
L1	1.27	1.65	0.049	0.065
L2	1.30	1.78	0.050	0.070
R	0.4	typ.	0.0)15
V2	0°	8°	0°	8°

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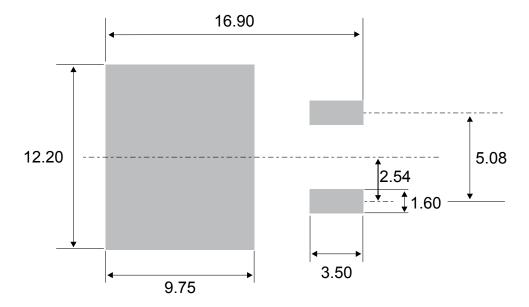


Figure 11. D²PAK Recommended footprint

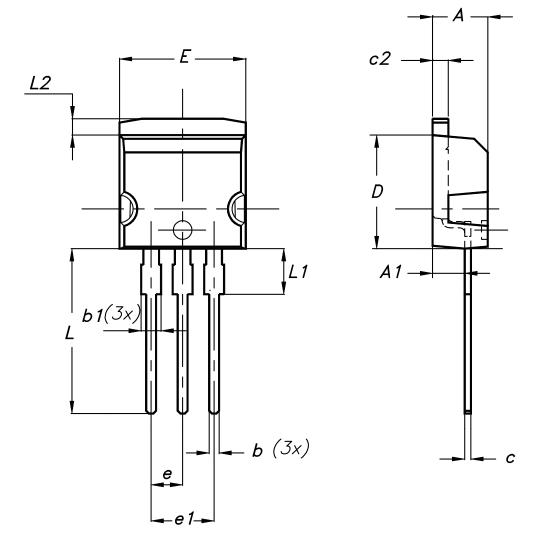
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2.2 I²PAK package information

- Epoxy meets UL 94,V0
- Cooling method: by conduction (C)

Figure 12. I²PAK package outline



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Table 5. I²PAK package mechanical data

	Dimensions				
Ref.	Millimeters		Inches (for re	ference only)	
	Min.	Max.	Min.	Max.	
Α	4.40	4.60	0.173	0.181	
A1	2.40	2.72	0.094	0.107	
b	0.61	0.88	0.024	0.035	
b1	1.14	1.70	0.044	0.067	
С	0.49	0.70	0.019	0.028	
c2	1.23	1.32	0.048	0.052	
D	8.95	9.35	0.352	0.368	
е	2.40	2.70	0.094	0.106	
e1	4.95	5.15	0.195	0.203	
E	10.00	10.40	0.394	0.409	
L	13.00	13.00 14.00		0.551	
L1	3.50	3.50 3.93 0.138		0.155	
L2	1.27	1.40	0.050	0.055	

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2.3 TO-220AB package information

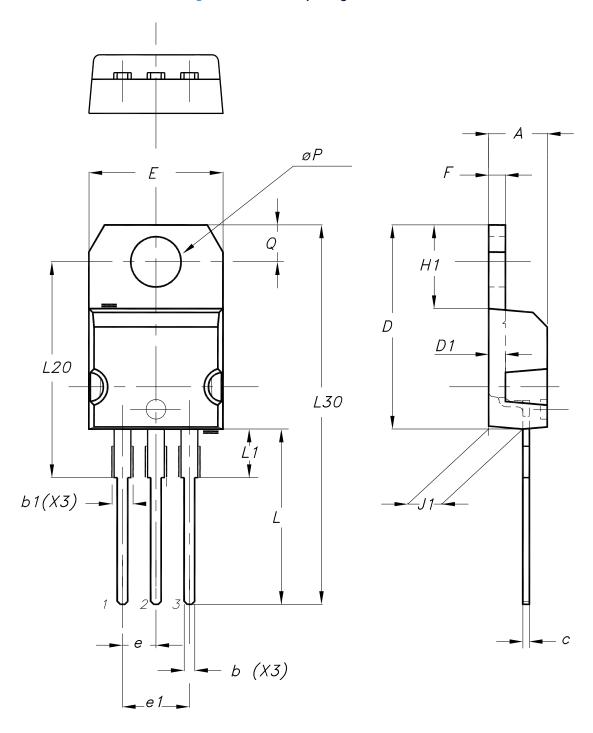
• Cooling method: by conduction (C)

• Epoxy meets UL 94,V0

Recommended torque value: 0.55 N·m

• Maximum torque value: 0.7 N·m

Figure 13. TO-220AB package outline



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Table 6. TO-220AB package mechanical data

	Dimensions			
Ref.	Millim	eters	Inch	ies
	Min.	Max.	Min.	Max.
Α	4.40	4.60	0.173	0.181
b	0.61	0.88	0.240	0.035
b1	1.14	1.55	0.045	0.061
С	0.48	0.70	0.019	0.028
D	15.25	15.75	0.600	0.620
D1	1.27	typ.	0.050 typ.	
E	10.00	10.40	0.394	0.409
е	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
F	1.23	1.32	0.048	0.052
H1	6.20	6.60	0.244	0.260
J1	2.40	2.72	0.094	0.107
L	13.00	14.00	0.512	0.551
L1	3.50	3.93	0.138	0.155
L20	16.40 typ.		0.646	typ.
L30	28.90 typ.		1.138	typ.
θР	3.75	3.85	0.148	0.152
Q	2.65	2.95	0.104	0.116

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2.4 TO-220FPAB package information

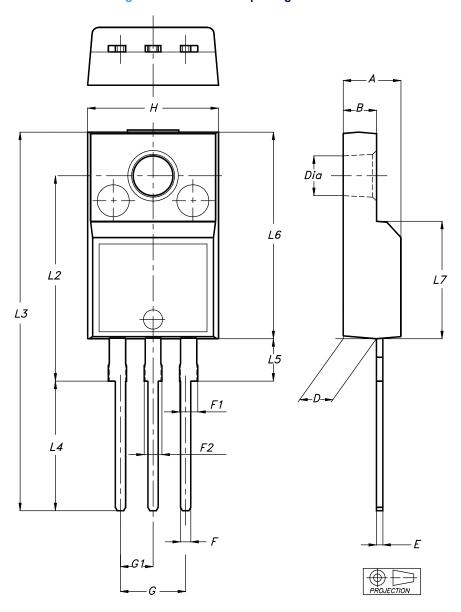
Epoxy meets UL 94,V0

Cooling method: by conduction (C)

• Recommended torque value: 0.55 N·m

Maximum torque value: 0.70 N·m

Figure 14. TO-220FPAB package outline



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Table 7. TO-220FPAB package mechanical data

	Dimensions			
Ref.	Millin	neters	Inches (for re	ference only)
	Min.	Max.	Min.	Max.
А	4.40	4.60	0.1739	0.1818
В	2.50	2.70	0.0988	0.1067
D	2.50	2.75	0.0988	0.1087
Е	0.45	0.70	0.0178	0.0277
F	0.75	75 1.00 0.0296 0.0		0.0395
F1	1.15	1.70	1.70 0.0455 0.06	
F2	1.15	1.70	1.70 0.0455 0.067	
G	4.95	5.20 0.1957 0		0.2055
G1	2.40	2.70 0.0949 0		0.1067
Н	10.00	10.40 0.3953		0.4111
L2	16.0	16.00 typ. 0.6324 typ.		4 typ.
L3	28.60	30.60	1.1304	1.2095
L4	9.80	10.60	0.3874	0.4190
L5	2.90	3.60	0.1146	0.1423
L6	15.90	16.40	0.6285	0.6482
L7	9.00	9.30	9.30 0.3557 0.3676	
Dia	3.00	3.20	0.1186	0.1265

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3 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS20H100CT	STPS20H100CT	TO-220AB	1.95 g	50	Tube
STPS20H100CFP	STPS20H100CFP	TO-220FPAB	1.90 g	50	Tube
STPS20H100CR	STPS20H100CR	I ² PAK	1.50 g	50	Tube
STPS20H100CG	STPS20H100CG	D ² PAK	1.48 g	50	Tube
STPS20H100CG-TR	STPS20H100CG	D ² PAK	1.48 g	1000	Tape and reel

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Revision history

Table 9. Document revision history

Date	Revision	Changes
Jul-2003	4G	Previous release
21-Mar-2007	5	Removed ISOWATT package
10-Sep-2007	6	Reformatted cover page to current standards - no technical changes. Updated dimensions A1, b, b1, c, c2, L, and L1 in Table 8.
22-Sep-2011	7	Updated Table 8.
21-May-2015	8	Updated features, and packages silhouette in cover page. Updated Section 1: "Characteristics" and Section 1.1: "Characteristics (curves)". Updated Section 2.2: "D²PAK package information".
16-Apr-2018	9	Updated I ² PAK package mechanical data.
20-Jan-2020	10	Updated Section 1 Characteristics and Table 8. Ordering information. Added Section Applications.

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